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Kind regards,

Team Nexperia

BAT85

Schottky barrier single diode

24 July 2012

Product data sheet

1. Product profile

1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a hermetically-sealed subminiature SOD68 (DO-34) package. The diode is suitable for mounting on a 2 E (5.08 mm) pitch.

1.2 Features and benefits

- Low forward voltage
- Guard ring protected
- · Hermetically-sealed leaded glass package

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Blocking diodes

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{F(AV)}	average forward current	$\delta \le 0.5$; f = 20 kHz; PCB mounting, lead length = 4 mm; half sine wave	-	-	200	mA
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	k a	к -]() - А
2	А	anode	DO-34 (SOD68)	aaa-003679





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3. Ordering information

Table 3. Ordering information

Type number	Package	age					
	Name	Description	Version				
BAT85	DO-34	hermetically sealed glass package; axial leaded; 2 leads	SOD68				

4. Marking

Table 4. Marking codes

Type number	Marking code
BAT85	marking band

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Mi	n I	Max	Unit
V _R	reverse voltage		-		30	V
I _F	forward current		-		200	mA
I _{F(AV)}	average forward current	$\delta \le 0.5$; f = 20 kHz; PCB mounting, lead length = 4 mm; half sine wave	-		200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	-		300	mA
I _{FSM}	non-repetitive peak forward current	$t_p \le 10 \text{ ms; } T_{j(init)} = 25 ^{\circ}\text{C}$	-		5	Α
Tj	junction temperature		-		125	°C
T _{amb}	ambient temperature		-6	5	125	°C
T _{stg}	storage temperature		-6	5	150	°C

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	320	K/W

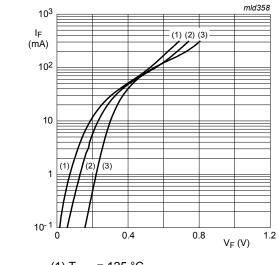
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 0.1 mA; T _{amb} = 25 °C	-	-	240	mV
		I _F = 1 mA; T _{amb} = 25 °C	-	-	320	mV
		I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV
		I _F = 30 mA; T _{amb} = 25 °C	-	-	500	mV
		I _F = 100 mA; T _{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V _R = 25 V; T _{amb} = 25 °C	-	-	2	μA
C _d	diode capacitance	f = 1 MHz; T _{amb} = 25 °C; V _R = 1 V	-	-	10	pF
t _{rr}	reverse recovery time	I_F = 10 mA; I_R = 10 mA; R_L = 100 Ω; $I_{R(meas)}$ = 1 mA; I_{amb} = 25 °C	-	-	4	ns

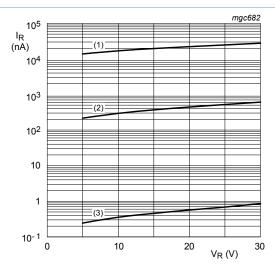




(2)
$$T_{amb}$$
 = 85 °C

(3)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 1. Forward current as a function of forward voltage; typical values



- (1) T_{amb} = 85 °C
- (2) T_{amb} = 25 °C
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 2. Reverse current as a function of reverse voltage; typical values

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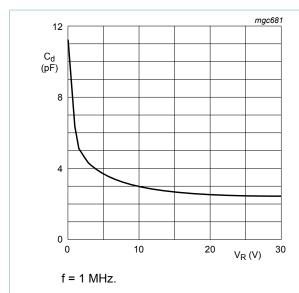


Fig. 3. Diode capacitance as a function of reverse voltage; typical values

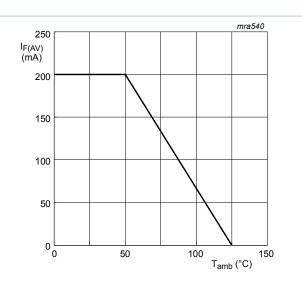
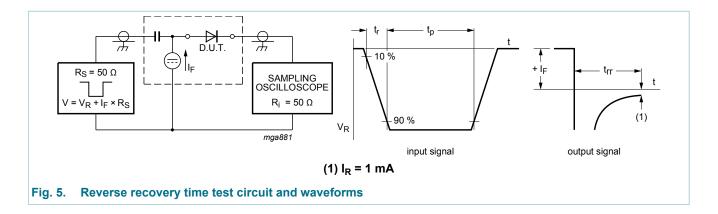


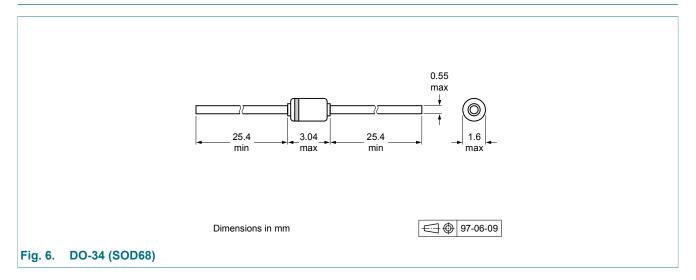
Fig. 4. Average forward current as a function of ambient temperature; typical values

8. Test information



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9. Package outline



10. Revision history

Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BAT85 v.5	20120724	Product data sheet	-	BAT85 v.4
Modifications:	of NXP Semicol Legal texts have Section "Markin Package outline	e been adapted to the new c	ompany name where ap	propriate.
BAT85 v.4	20000525	Product specification	-	BAT85 v.3
BAT85 v.3	19960320	Product specification	-	-

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11.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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